ET

November 24th, 1959

COCOM Document No. 3713.60/1

COORDINATING COMMITTEE

RECORD OF DISCUSSION

ON

ITEM 1360 - EQUIPMENT SPECIALLY DESIGNED FOR PURIFYING

AND PROCESSING SILICON AND GERMANIUM

13th and 17th NOVEMBER, 1959

Present:

Belgium (Luxembourg), Canada, France, Germany, Italy, Japan, Netherlands, United Kingdom, United States.

References: COCOM Documents 3715.00/1, 1959 Review W.P.4 and W.P.4/1360.

1. The UNITED STATES Delegation proposed that this item be redefined so as to read:

"Equipment for the manufacture of semi-conductor materials as follows:

- (a) Equipment specially designed for the production or processing of dendritic forms of any semi-conductor material, or combination thereof, suitable for use in diodes or transistors;
- (b) Equipment n.e.s., specially designed for purifying and processing silicon and germanium except equipment designed for the zone purification of germanium.
- NOTE: The term "dendritic" signifies a ribbon-like product of semi-conductor material which may be drawn in various widths, thicknesses and lengths and which may represent processing stages from a relatively pure form of the material through advanced stages of treatment."
- 2. This proposal was accepted by the GERMAN, NETHERLANDS and UNITED KINGDOM Delegations. The FRENCH, ITALIAN and JAPANESE Delegations accepted ad referendum.
- 3. <u>CONCLUSION</u>. The Committee agreed that the study of this item would only be resumed in the course of the second round of the review in the event of non-confirmation of the <u>ad referendum</u> agreement.

